



迈拓电子
MAITUO ELECTRONIC

PBSS5350T

Descriptions

Silicon PNP transistor in a SOT-23 Plastic Package.

Features

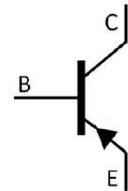
Low $V_{CE(sat)}$, high current.

Applications

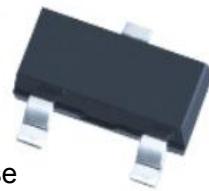
General purpose switching and muting

LCD back-lighting

Supply line switching circuits.



3 Collector



1 Base

2 Emitter

SOT23

h_{FE} Classifications & Marking

h_{FE} Range	>200
Marking	ZDH



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Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-50	V
Collector to Emitter Voltage	V_{CEO}	-50	V
Emitter to Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-2	A
Peak Collector Current	I_{CM}	-5	A
Base Current	I_B	-0.5	A
Total Power Dissipation	P_{tot}	300	mW
Total Power Dissipation	P_{tot} (注1、2)	1.2	W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-65~150	°C

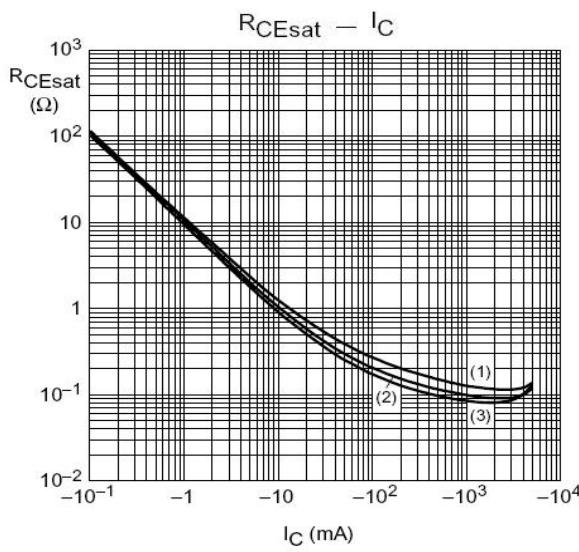
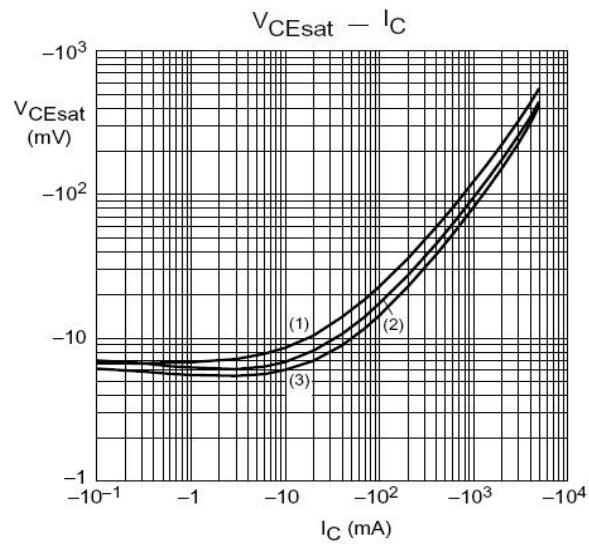
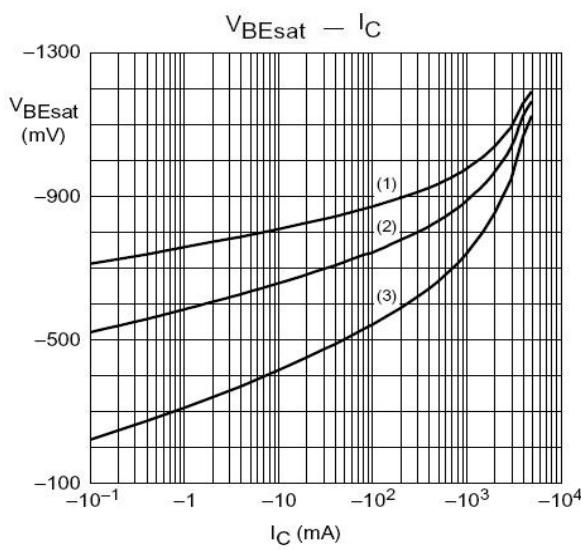
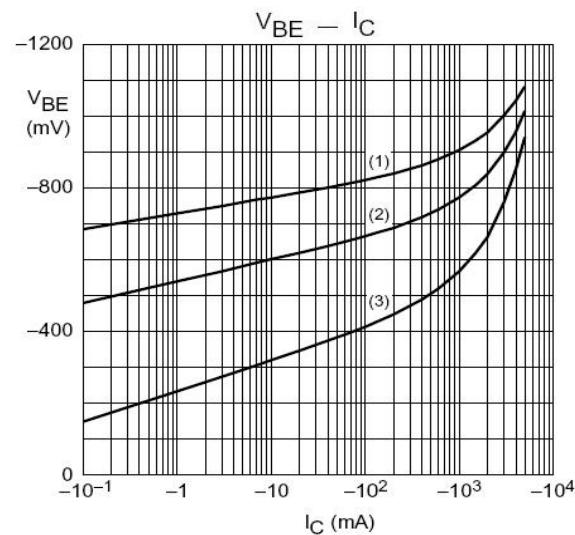
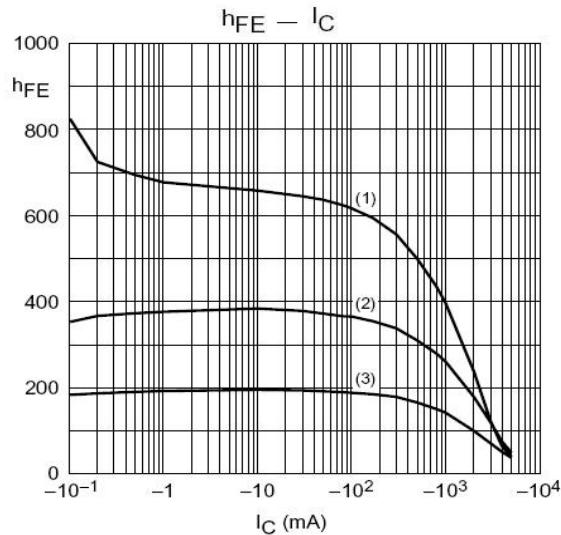
Electrical Characteristics(Ta=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-Off Current	I_{CBO}	$V_{CB}=-50V \quad I_E=0$			-100	nA
		$V_{CB}=-50V \quad I_E=0$ $T_j=150^\circ C$			-50	μA
emitter Cut-Off Current	I_{EBO}	$V_{EB}=-5.0V \quad I_C=0$			-100	nA
DC Current Gain	$h_{FE(1)}$	$V_{CE}=-2.0V \quad I_C=-100mA$	200			
	$h_{FE(2)}$	$V_{CE}=-2.0V \quad I_C=-500mA$	200			
	$h_{FE(3)}^*$	$V_{CE}=-2.0V \quad I_C=-1.0A$	200			
	$h_{FE(4)}^*$	$V_{CE}=-2.0V \quad I_C=-2.0A$	130			
	$h_{FE(5)}^*$	$V_{CE}=-2.0V \quad I_C=-3.0A$	80			
Collector-Emitter Saturation Voltage	$V_{CE(sat)(1)}^*$	$I_C=-500mA \quad I_B=-50mA$			-80	mV
	$V_{CE(sat)(2)}^*$	$I_C=-2.0A \quad I_B=-100mA$			-320	mV
Equivalent On-Resistance	$R_{CE(sat)}^*$	$I_C=-2.0A \quad I_B=-200mA$		90	135	mΩ
Base-Emitter Saturation Voltage	$V_{BE(sat)}^*$	$I_C=-2.0A \quad I_B=-100mA$			-1.1	V
		$I_C=-3.0A \quad I_B=-300mA$			-1.2	V
Base-Emitter Voltage	$V_{BE(ON)}^*$	$V_{CE}=-2.0V \quad I_C=-1.0A$			-1.2	V
Transition Frequency	f_T	$V_{CE}=-5.0V \quad I_C=-100mA$ $f=100MHz$	100			MHz
Collector Capacitance	C_C	$V_{CB}=-10V \quad I_E=0$ $f=1.0MHz$			35	pF



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Electrical Characteristic Curve



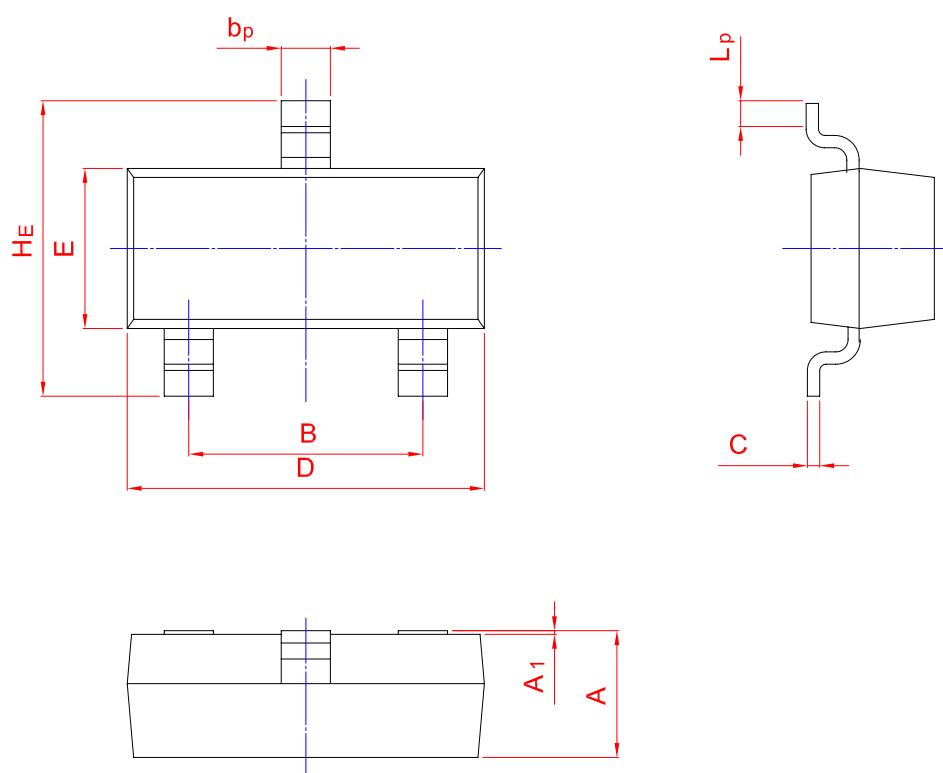


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PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23



UNIT	A	B	b_p	C	D	E	H_E	A_1	L_p
mm	1.40 0.95	2.04 1.78	0.50 0.35	0.19 0.08	3.10 2.70	1.65 1.20	3.00 2.20	0.100 0.013	0.50 0.20